NSN 5962-01-246-8722

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View Online at https://aerobasegroup.com/nsn/5962-01-246-8722

Body Length:
2.096 inches
Body Width:
0.620 inches
Body Height:
0.210 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and programmable and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
38 input
Case Outline Source And Designator:
D-5 mil-m-38510
Current Rating Per Characteristic:
10.00 microamperes forward current, nonrepetitive, peak total value minor
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
8.0 volts power source
Time Rating Per Chacteristic:
250.00 nanoseconds propagation delay time, low to high level output and 250.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Pal
Special Features:
Nuclear hardness critical items
Nuclear Hardness Critical Feature:
Hardened
Test Data Document:
14933-84066 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

20 printed circuit

Terminal Type And Quantity:

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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